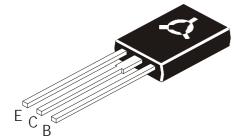


BD175BD176BD177BD178BD179BD180NPNPNP

TO126 Plastic Package

EPITAXIAL SILICON POWER TRANSISTORS



Intended for use in Medium Power Linear Switching Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BD175	BD177	BD179	UNIT
		BD176	BD178	BD180	
Collector -Emitter Voltage	V _{CEO}	45	60	80	V
Collector -Base Voltage	V _{CBO}	45	60	80	V
Emitter Base Voltage	V _{EBO}		5.0		V
Collector Current	Ι _C	3.0			А
Collector Peak Current	I _{CM}	7.0			А
Power Dissipation @ T _a =25 ^o C	P _D	1.25			W
Derate above 25°C			10		mW/ºC
Power Dissipation @ T _c =25 ^o C	P _D		30		W
Operating and Storage Junction Temperature Range	T _j , T _{stg}		- 65 to +150		°C

THERMAL CHARACTERISTICS

Junction to Ambient in free air	R _{th (j-a)}	100	°C/W
Junction to Case	R _{th (j-c)}	4.16	°C/W

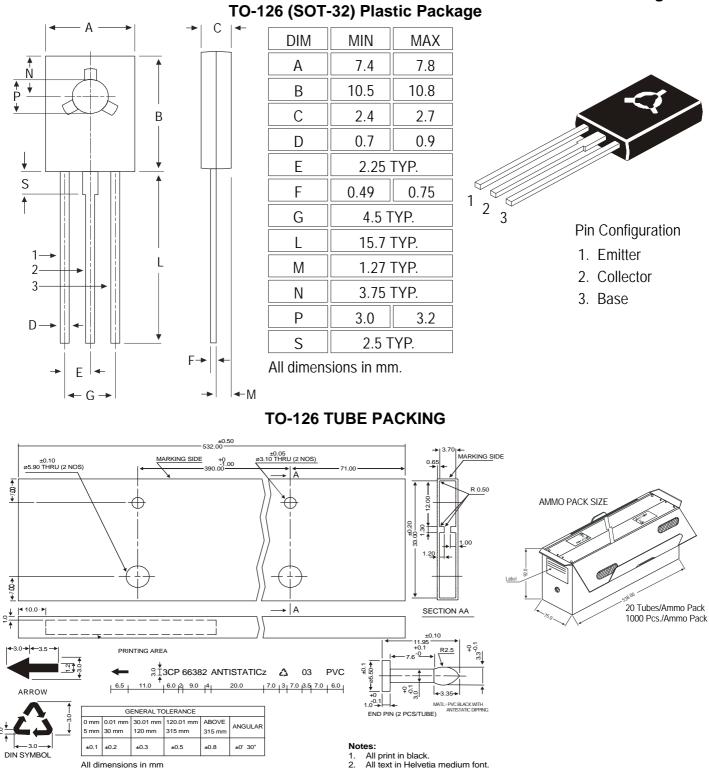
ELECTRICAL CHARACTERISTICS (T_c=25^oC unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION		MIN	MAX	UNIT
Collector Cut off Current	I _{CBO}	V _{CB} =45V, I _E =0	BD175/76		100	μA
		V _{CB} =60V, I _E =0	BD177/78		100	μA
		V _{CB} =80V, I _E =0	BD179/80		100	μA
Emitter Cut off Current	I _{EBO}	V_{EB} =5V, I_{C} =0			1.0	mA
Collector Emitter Sustaining Voltage	*V _{CEO (sus)}	I _C =100mA, I _B =0	BD175/76	45		V
			BD177/78	60		V
			BD179/80	80		V
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =1A, I _B =0.1A			0.8	V
Base Emitter on Voltage	*V _{BE (on)}	I _C =1A, V _{CE} =2V			1.3	V
DC Current Gain	*h _{FE}	I _C =150mA, V _{CE} =2V		40		
		I_{C} =1A, V_{CE} =2V		15		
	*h _{FE} Group	I _C =150mA, V _{CE} =2V	- 6	40	100	
			- 10	63	160	
		Only BD175/76/79	- 16	100	250	
Transition Frequency	f _⊤	I _C =250mA, V _{CE} =10V		3.0		MHz

*Pulse test:- Pulse width=300ms, Duty cycle=1.5%

BD175	BD176
BD177	BD178
BD179	BD180
NPN	PNP

TO126 Plastic Package



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-126 Bulk	500 pcs/polybag	340 gm/500 pcs	3" x 7.5" x 7.5"	2K	17" x 15" x 13.5"	32K	31 kgs
TO-126 Tube	50 pcs/tube	73 gm/50 pcs	3" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	15 kgs

BD175	BD176
BD177	BD178
BD179	BD180
NPN	PNP

TO126 Plastic Package

Disclaimer

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CDIL is a registered Trademark of Continental Device India Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-2579 6150 Fax + 91-11-2579 9569, 2579 5290 e-mail sales@cdil.com www.cdil.com www.cdilsemi.com

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